

HS2403

20A, High Efficiency Power Module

FEATURES:

- High Power Density Power Module
- Maximum Load:20A(22A@ Note 8)
- Input Voltage Range from 4.5V to 20.0V
- Output Voltage Range from 0.8V to 5.5V
- 96% Peak Efficiency
- Parallel Three Modules for 60A Output Current with Forced Current Sharing
- Current Mode Control
- Protections (OCP, OVP, UVP, OTP, Non-latching)
- Programmable Soft Start with Pre-bias Output Start-Up
- Programmable Switching Frequency
- Power Good Indication
- Stack-QFN Package (14.5mm*14.5mm*7.45mm)
- Pb-free Available (RoHS compliant)
- MSL 3, 245C Reflow

APPLICATIONS:

- General Buck DC/DC Conversion
- DC Distributed Power System
- Telecom and Networking Equipments
- Servers System
- Cell Phones / PDAs / Palmtops

GENERAL DESCRIPTION:

The HS2403 is a high frequency, high power density and complete DC/DC power module. The PWM controller, power MOSFETs and most of support components are integrated in one hybrid package. Additional, a new patent technology is adopted to stack power choke on the hybrid module in order to achieve high power density.

The module allows a modular power supply design where multiple modules can be connected in parallel to achieve the desired output power capability if the output power requirement cannot be provided by one module. Besides, HS2403 is an easy to use DC/DC power module, only input capacitors and output capacitors need to design for all kinds of applications.

The compact package enables utilization of unused space on the bottom of PC boards for needing highly space density applications. The HS2403 is packaged in a thermally enhanced, compact and low profile QFN package suitable for automated assembly by standard surface mount equipment. The HS2403 is Pb-free and RoHS compliance.

TYPICAL APPLICATION CIRCUIT & PACKAGE:

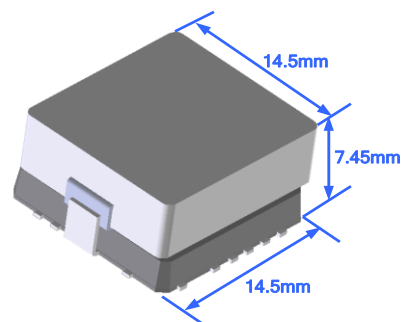
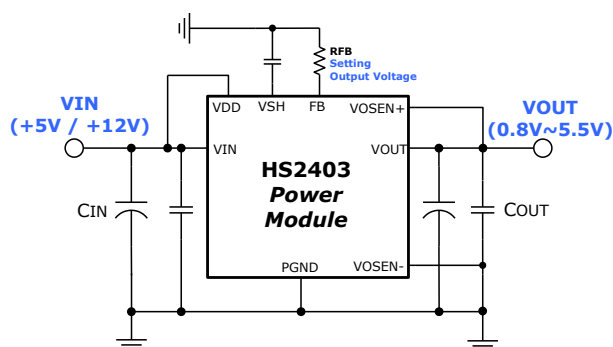


TABLE 1: OUTPUT VOLTAGE SETTING

Vout	0.9V	1.0V	1.2V	1.5V	1.8V	2.5V	3.3V	5V
RFB (Ohm)	34.8k	23.2k	14k	8.66k	6.34k	3.83k	2.61k	1.62k



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ORDER INFORMATION:

Part Number	Ambient Temp. Range (°C)	Package (Pb-Free)	MSL	Note
HS2403	-40 ~ +85	Stack-QFN 20Ld.	Level 3	-

Order Code	Packing	Quantity
HS2403	Tray	90
HS2403-T	Tape and reel	350

SIMPLIFIED INTERNAL BLOCK DIAGRAM:

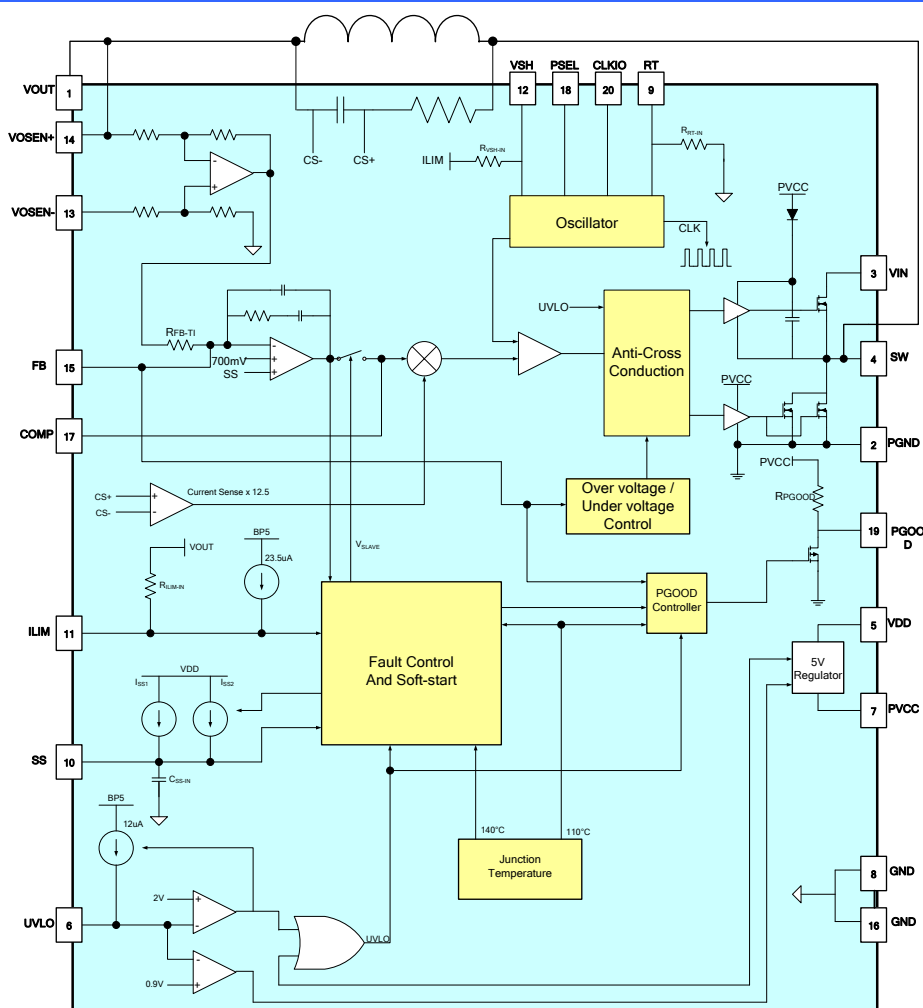
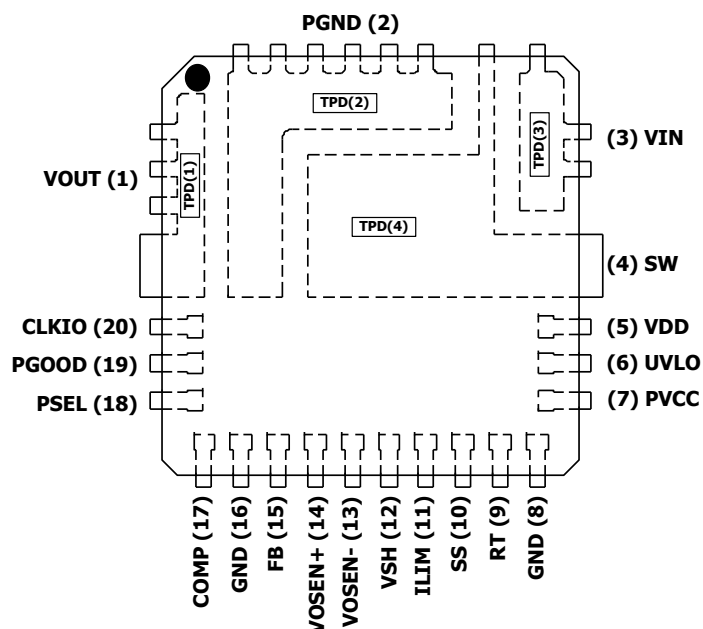


FIG.1 INTERNAL BLOCK DIAGRAM

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PIN CONFIGURATION:



Top View

PIN DESCRIPTION:

Symbol	Pin No.	Description
VOUT (TPD 1)	1	Power output pin. Connect to output and using for heat transferring to heat dissipation layer by Vias connection. Place the output capacitors as closely as possible to this pin.
PGND (TPD 2)	2	Power ground pin. It needs to connect one or more ground plane directly and using for heat transferring to heat dissipation layer by Vias connection. Place the input ceramic type and output capacitors as closely as possible to this pin. If voltage spike stress and EMI considered, the snubber circuit can be as closely as possible connected to this pin that will absorb the spike and ringing.
VIN (TPD 3)	3	Power input pin. It needs to connect input rail and using for heat transferring to heat dissipation layer by Vias connection. Place the input ceramic type capacitor as closely as possible to this pin.
SW (TPD 4)	4	Switching node pin. Node of high-side and low-side MOSFETs and output inductor connection. Using for heat transferring to heat dissipation layer by Vias connection. For electrically, if voltage spike stress and EMI considered, the snubber circuit can be as closely as possible connected to this pin that will absorb the spike and ringing well.

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PIN DESCRIPTION: (Cont.)

Symbol	Pin No.	Description
VDD	5	Supply voltage pin for internal LDO device input. This LDO input can be supplied by external source or VIN directly. It needs to connect a 4.7ohms resistor and 2.2uF ceramic capacitor RC filter to power ground plane directly and place this capacitor as closely as possible to this pin.
UVLO	6	UVLO input for the device. A resistor divider from VDD sets the turn on voltage for the device. Below this voltage, the device is in a low quiescent current state. Pulling this pin to ground shuts down the device, and is used as system shutdown method.
PVCC	7	Output of internal LDO device. This is the power input for the drivers and bootstrap circuit. The 5.3V output on this pin is used for external circuitry as long as the total current required to drive the gate of the MOSFET and external loads is less than 50mA. Connect a 2.2uF capacitor from this pin to PGND.
GND	8, 16	Signal ground pin for overall signal reference used. No power level current should be allowed to flow through the GND pin copper areas on the board. Besides, it should have itself ground plane to cover the overall signal trace then connect to power ground plane directly by via.
RT	9	Switching frequency programming pin. It has an integrated internal 91k Ω resistor (R_{RT-IN}) between RT and GND pin for 300k Hz typical operation. One can also connect external resistor (R_{RT-EX}) between this pin and GND pin to increase the switching frequency. Place this resistor as closely as possible to this pin. If this pin is connected to VDD or PVCC, the device is a clock slave and gets its time base from CLKIO of the clock master device. Phase addressing is done on PSEL.
SS	10	Soft-start input. This pin determines the startup ramp time for the converter as well as over current and other fault recovers timing. The voltage at this pin is applied as a reference to the error amplifier. While this voltage is below the precision 0.7V reference, it acts as the dominant reference to the error amp providing a closed loop startup. After is rises above the 0.7 V precision references, the 0.7V precision reference dominates and the output regulates at the programmed level. In case of an over current event, the converter attempts to restart after a period of time defined by seven soft-start cycles. Additionally this pin is used to configure the chip as a voltage loop master or slave. If the pin is tied to VDD or PVCC at power up, the device is in voltage loop slave mode. Otherwise, the device is a voltage loop master. It has an integrated internal 22nF capacitor (C_{SS-IN}) between SS and GND pin for 1mS typical operation.
ILIM	11	Programs the over current limit of the device. Connecting a resistor from this pin to VSH and another to VOUT on the voltage loop master sets a voltage above VSH. COMP is not allowed to exceed this voltage. If the load current requirements force COMP to this level for seven clock cycles, an over current event is declared, and the system shuts down and enter a hiccup fault recover mode. The controller attempts to restart after a time period given by seven soft-start cycles. It has an integrated internal 84.5 k Ω resistor ($R_{ILIM-IN}$) between ILIM and VOUT pin for around 40A maximum current limits.

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PIN DESCRIPTION: (Cont.)

Symbol	Pin No.	Description
VSH	12	This pin is either an input or an output. If the device is configured as a voltage loop master the valley voltage is output on this pin and is distributed to the slave devices. If configured as a voltage loop slave, the master VSH pin is connected here and the device uses the master valley voltage reference to improve current sharing. Besides, this pin also multi-function with ILIM pin for over current setting used. It has an integrated internal 2 Meg Ω resistor (R_{VSH-IN}) between VSH and ILIM pin for around 40A maximum current limits.
VOSEN-	13	Negative input to the remote sense amplifier. Amplifier is fixed of 1 differential mode and is used for output voltage sensing at the load to eliminate distribution drops. This pin should be directly connected to the point of load where the voltage regulation is required. CAUTION: Do not leave this pin open.
VOSEN+	14	Positive input to the remote sense amplifier. Amplifier is fixed of 1 differential mode and is used for output voltage sensing at the load to eliminate distribution drops. This pin should be directly connected to the point of load where the voltage regulation is required. CAUTION: Do not leave this pin open.
FB	15	Feedback input. Connect resistor between this pin and ground for adjusting output voltage. Place this resistor as closely as possible to this pin. Normally this pin is at the reference voltage of 700mV.
COMP/EN	17	Output of the error amplifier. It has integrated the type 2 compensation networking circuit.
PSEL	18	Phase select pin. For a clock master, a resistor from this pin to GND determines the CLKIO output. When configured as a clock slave, a resistor from the pin to GND selects the phase relationship that the slave has with the master. Allowing this pin to float causes the slave to drop off line to share the phase when current demands are light for improved overall efficiency.
PGOOD	19	Power good output. This open drain output pulls low when the device is in any state other than in normal regulation. Active soft-start, UVLO, over current, under voltage, overvoltage or over temperature warning causes this output to pull low. It has an integrated the pull high internal 10 k Ω resistor (R_{PGOOD}) between PVCC and this pin.
CLKIO	20	Clock and phase timing output while the device is configured as a clock master. In clock slave mode, the master CLKIO pin is connected to the slave CLKIO pin to provide time base information to the slave.

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ELECTRICAL SPECIFICATIONS:

CAUTION: Don not operate at or near absolute maximum rating listed for extended periods of time. This stress may adversely impact product reliability and result in failures not covered by warranty.

Parameter	Description	Min.	Typ.	Max.	Unit
■ Absolute Maximum Ratings					
VDD, UVLO, RT, SS to GND	Note 1	-0.3	-	+15.0	V
PVCC to GND		-0.3	-	+6.0	V
FB, COMP, VOSEN+, VOSEN- to GND		-0.3	-	+6.0	V
VSH, ILIM, PSEL, CLKIO to GND		-0.3	-	+6.0	V
PGOOD to GND		-0.3	-	+22.0	V
VIN to SW	Note 2	-1.2	-	+30	V
SW to PGND	Note 2	-1.0	-	+30	V
Tc		-	-	+110	°C
Tj		-40	-	+125	°C
Tstg		-40	-	+125	°C
ESD Rating	Human Body Model (HBM)	-	-	2k	V
	Machine Model (MM)	-	-	100	V
	Charge Device Model (CDM)	-	-	1k	V
■ Recommendation Operating Ratings					
VIN	Input Supply Voltage	+4.5	-	+20.0	V
VOUT	Output Voltage	+0.8	-	+5.5	V
VDD	Bias Supply Voltage	+4.5	-	+13.2	V
Ta	Ambient Temperature	-40	-	+85	°C
■ Thermal Information					
Rth(j-a)	Thermal resistance from junction to ambient. (Note 3)	-	13.5	-	°C/W

NOTES:

1. When the output voltage is 5V, the VDD operating voltage should above the output voltage 1V
2. V_{DS} (Drain to Source) specification for internal high-side and low-side MOSFETs.
3. $R_{th(j-a)}$ is measured with the component mounted on an effective thermal conductivity test board on 0 LFM condition. The test board size is 80mm×80mm×1.6mm with 4 layers, 2oz. The test condition is complied with JEDEC E1J/JESD 51 Standards.

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ELECTRICAL SPECIFICATIONS: (Cont.)

Conditions: $T_A = 25^\circ\text{C}$, unless otherwise specified.

$V_{in}=12\text{V}$, $V_{out}=1.8\text{V}$, $C_{in}=22\mu\text{F}/\text{Ceramic}\times 3$, $C_{out}=100\mu\text{F}/\text{Ceramic}\times 4$

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
■ Input Characteristics						
$I_{Q(VIN)}$	Input supply bias current	$I_{out} = 0\text{A}$ $V_{in} = 12\text{V}$, $V_{out} = 1.8\text{V}$ $V_{DD} = 12\text{V}$	-	25	-	mA
$I_{S(VIN)}$	Input supply current	$I_{out} = 10\text{A}$ $V_{in} = 12\text{V}$, $V_{out} = 1.8\text{V}$ $V_{DD} = 12\text{V}$	-	1.7	-	A
■ Output Characteristics						
$I_{OUT(DC)}$	Output continuous current range	$V_{in}=12\text{V}$, $V_{out}=1.8\text{V}$	0	-	20	A
$\Delta V_{OUT}/\Delta V_{IN}$	Line regulation accuracy	$V_{in} = 6\text{V}$ to 12V $V_{out} = 1.8\text{V}$, $I_{out} = 0\text{A}$ $V_{out} = 1.8\text{V}$, $I_{out} = 10\text{A}$ $V_{DD} = 6\text{V}$ to 12V	-	0.1	-	%
$\Delta V_{OUT}/\Delta I_{OUT}$	Load regulation accuracy	$I_{out} = 0\text{A}$ to 10A $V_{in} = 12\text{V}$, $V_{out} = 1.8\text{V}$ $V_{DD} = 12\text{V}$	-	0.5	-	%
$V_{OUT(AC)}$	Output ripple voltage	$I_{out} = 10\text{A}$ $V_{in} = 12\text{V}$, $V_{out} = 1.8\text{V}$ $V_{DD} = 12\text{V}$	-	30	-	mVp-p
■ Dynamic Characteristics						
ΔV_{OUT-DP}	Voltage change for positive load step	$I_{out} = 0\text{A}$ to 10A Current slew rate = $2.5\text{A}/\mu\text{S}$ $V_{in} = 12\text{V}$, $V_{out} = 1.8\text{V}$ $V_{DD} = 12\text{V}$	-	140	-	mVp-p
ΔV_{OUT-DN}	Voltage change for negative load step	$I_{out} = 10\text{A}$ to 0A Current slew rate = $2.5\text{A}/\mu\text{S}$ $V_{in} = 12\text{V}$, $V_{out} = 1.8\text{V}$ $V_{DD} = 12\text{V}$	-	140	-	mVp-p
■ Control Characteristics						
V_{REF}	Reference voltage	Note 3	0.695	0.7	0.705	V
F_{OSC}	Oscillator frequency		261	300	339	kHz
R_{FB-TI}	Internal resistor between VOUT and FB pins		9.9	10	10.1	k Ω
V_{UVLO}	PVCC regulator enable	Note 3	0.8	0.9	1.5	V
	PWM switching enable	Note 3	1.9	2	2.1	V

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ELECTRICAL SPECIFICATIONS: (Cont.)

Conditions: $T_A = 25^\circ\text{C}$, unless otherwise specified.

$V_{in}=12\text{V}$, $V_{out}=1.8\text{V}$, $C_{in}=22\mu\text{F}/\text{Ceramic}\times 3$, $C_{out}=100\mu\text{F}/\text{Ceramic}\times 4$

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
■ Control Characteristics						
R_{PGOOD}	Internal resistor between PVCC and PGOOD pins		9.9	10	10.1	$k\Omega$
V_{FBPG-H}	PGOOD upper threshold voltage	Note 3	0.764	0.787	0.798	V
V_{FBPG-L}	PGOOD lower threshold voltage	Note 3	0.591	0.611	0.626	V
V_{PG-H}	PGOOD voltage High	PGOOD Open / No Fault	-	PVCC	-	V
V_{PG-L}	PGOOD voltage Low	PGOOD Open / Fault	-	0.35	0.4	V
C_{SS-IN}	Internal capacitor between SS and GND pins		19.8	22	24.2	nF
I_{SS1}	Soft start current source 1	Note 3	6.5	7.5	8.2	μA
I_{SS2}	Soft start current source 2	Note 3	12	15	17	μA
■ Fault Protection						
V_{FB-U}	FB under voltage threshold	Note 3	565	580	595	mV
V_{FB-O}	FB over voltage threshold	Note 3	792	810	828	mV
T_{TSD}	Shutdown temperature	Note 3 (T_J of internal PWM IC)	126	135	144	$^\circ\text{C}$

NOTES:

- Parameters guaranteed by PWM IC vendor design and test prior to module assembly.

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TYPICAL PERFORMANCE CHARACTERISTICS:

Conditions: $T_A = 25^\circ\text{C}$, unless otherwise specified.

$C_{in}=22\mu\text{F}/\text{Ceramic}\times 3$, $C_{out}=100\mu\text{F}/\text{Ceramic}\times 4$

Test Board Information: 80mm×80mm×1.6mm, 4 layers, 2oz.

NOTES:

- The output ripple measurement is short loop probing and 20MHz bandwidth limited.
- Load Current Slew Rate=2.5A/uS

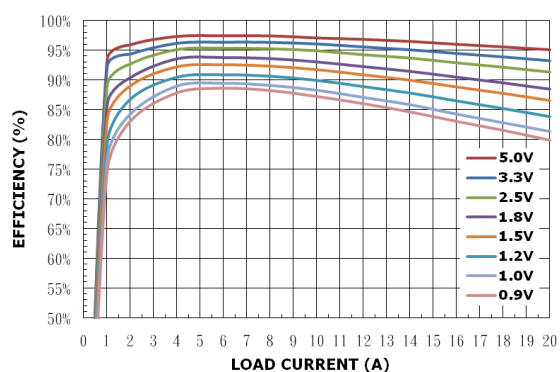


FIG.2 EFFICIENCY V.S. LOAD CURRENT
(VIN=12V, VDD=12V)

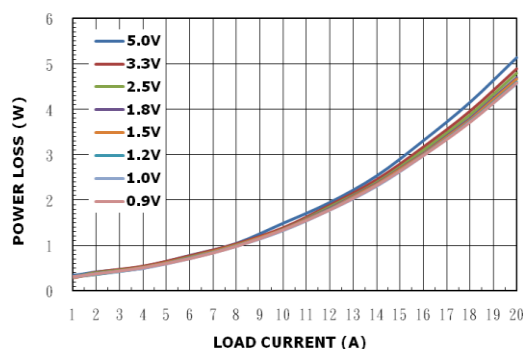


FIG.3 POWER LOSS V.S. LOAD CURRENT
(VIN=12V, VDD=12V)

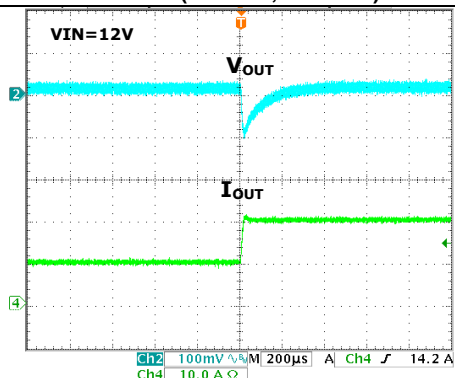


FIG.4 5.0 VOUT TRANSIENT RESPONSE,
at 10A to 20A LOAD CURRENT

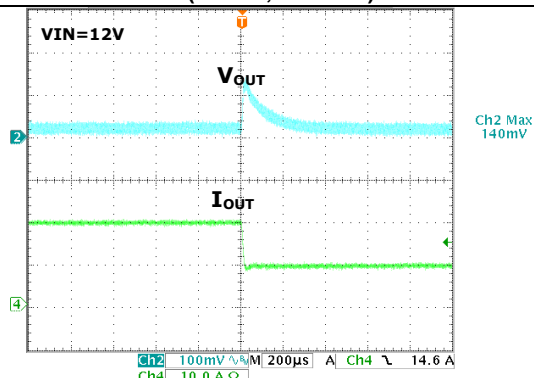


FIG.5 5.0 VOUT TRANSIENT RESPONSE,
at 20A to 10A LOAD CURRENT

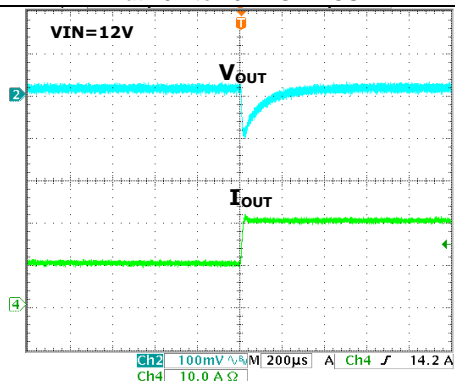


FIG.6 3.3 VOUT TRANSIENT RESPONSE,
at 10A to 20A LOAD CURRENT

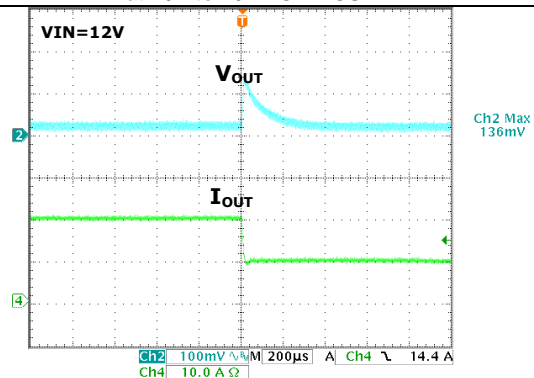


FIG.7 3.3 VOUT TRANSIENT RESPONSE,
at 20A to 10A LOAD CURRENT

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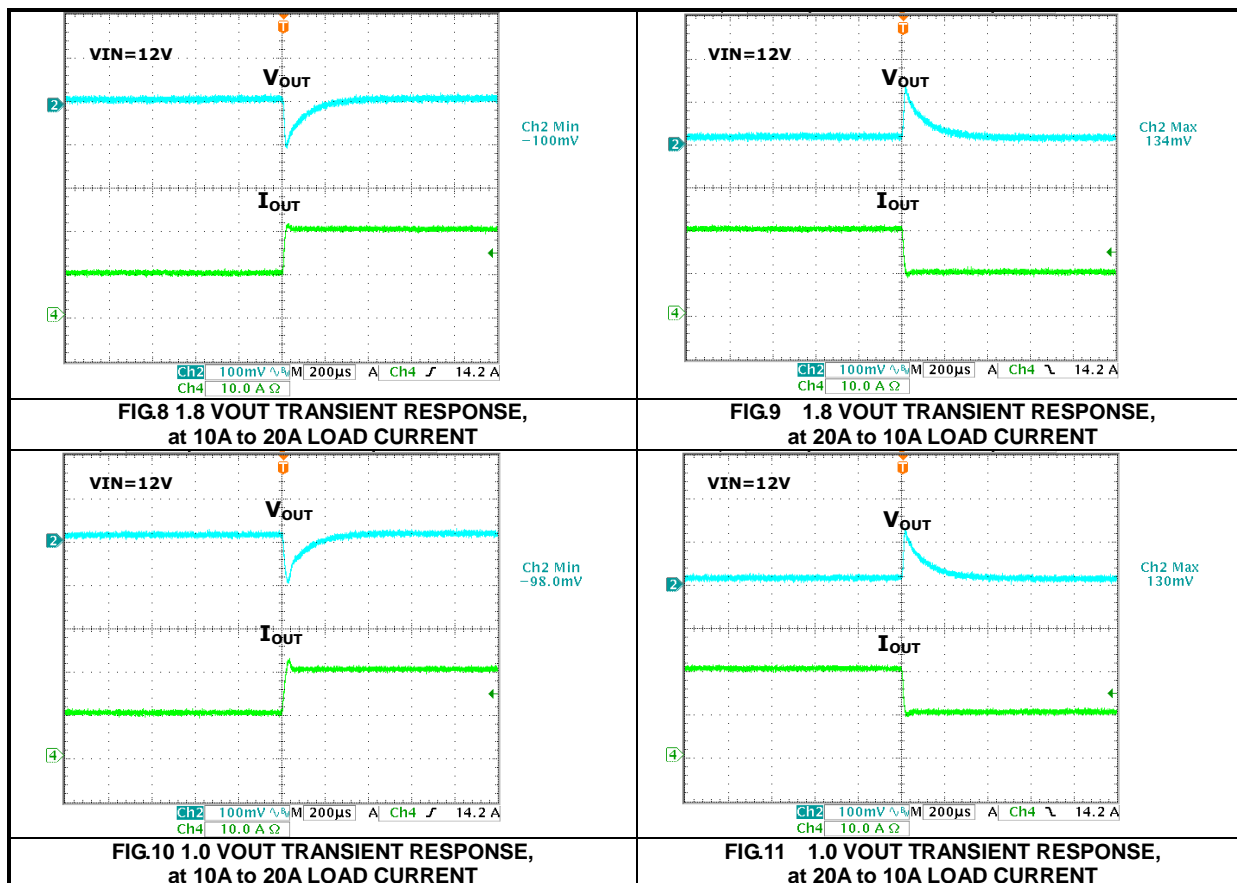
20A, High Efficiency Power Module

TYPICAL PERFORMANCE CHARACTERISTICS:

Conditions: $T_A = 25^\circ\text{C}$, unless otherwise specified.

$C_{in}=22\mu\text{F}/\text{Ceramic}\times 3$, $C_{out}=100\mu\text{F}/\text{Ceramic}\times 4$

Test Board Information: 80mm \times 80mm \times 1.6mm, 4 layers, 2oz.



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20A, High Efficiency Power Module

TYPICAL PERFORMANCE CHARACTERISTICS:

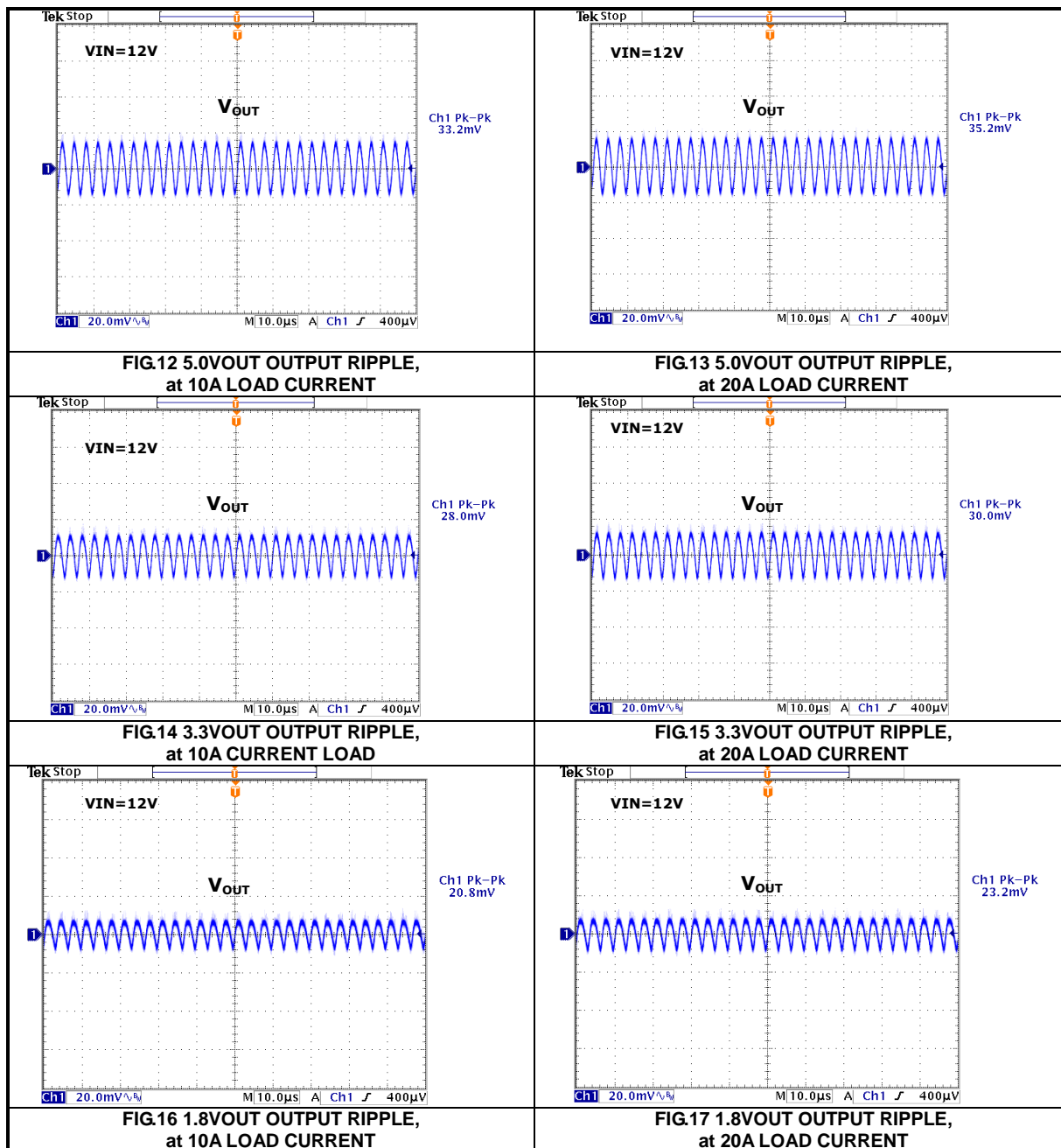
Conditions: $T_A = 25^\circ\text{C}$, unless otherwise specified.

$C_{in}=22\mu\text{F}/\text{Ceramic}\times 3$, $C_{out}=100\mu\text{F}/\text{Ceramic}\times 4$

Test Board Information: 80mm \times 80mm \times 1.6mm, 4 layers, 2oz.

NOTES:

7. The output ripple measurement is short loop probing and 20MHz bandwidth limited.



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APPLICATIONS INFORMATION:

REFERENCE CIRCUIT FOR GENERAL APPLICATION:

Individual Application

The Figure 18 shows the HS2403 application schematics for input voltage +5V or +12V. The VDD pin can connect to input supply directly by using a RC filter. If input voltage larger then +13.2V, please place a Zener diode between VDD and GND.

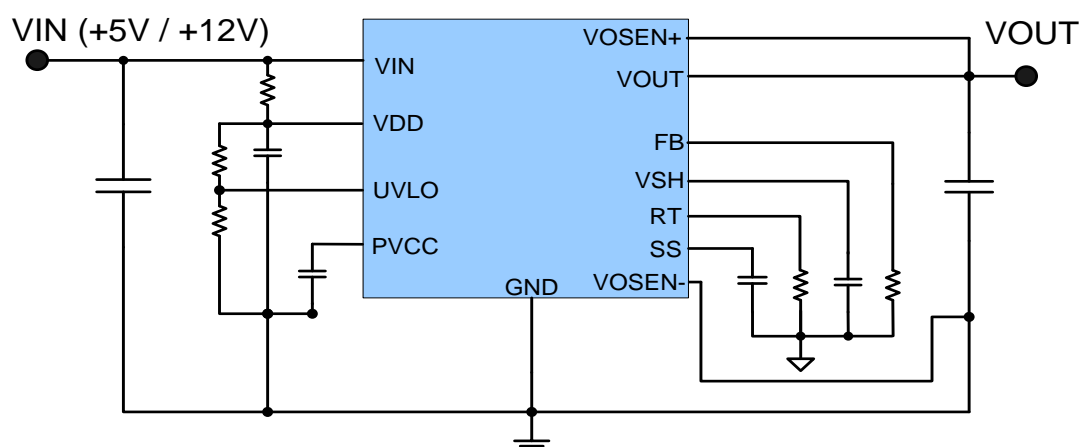


FIG.18 TYPICAL APPLICATION WITH SINGLE POWER SUPPLY

Safety Considerations

Certain applications and/or safety agencies may require fuses at the inputs of power conversion components. Fuses should also be used when there is the possibility of sustained input voltage reversal which is not current limited. For greatest safety, we recommend a fast blow fuse installed in the ungrounded input supply line. The installer must observe all relevant safety standards and regulations. For safety agency approvals, install the converter in compliance with the end-user safety standard.

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APPLICATIONS INFORMATION: (Cont.)

Single Output with 2-Phases Interleaved Parallel Application

The main benefits of using the HS2403 is the ability to parallel output power stages to achieve higher output currents and stack on controllers as needed. Phasing information is also shared among the controllers to minimize input ripple and RMS current in the input stage capacitors. Figure 19 show the controller configuration connections to implement a single output stacked configuration for 40A load sharing. The master controller is configured as a CLK master and as a voltage control loop master (SS and RT pin connections). The slave controllers are configured as CLK slaves (RT pin tied to VDD) and as voltage control loop slaves (SS pin tied to VDD). The PSEL pin selects the CLKIO operating mode for the device. The PSEL phase programming states defined in Table 2. In any system configured to have a CLK master and CLK slaves, a 10-k Ω resistor connected from CLKIO to GND is required.

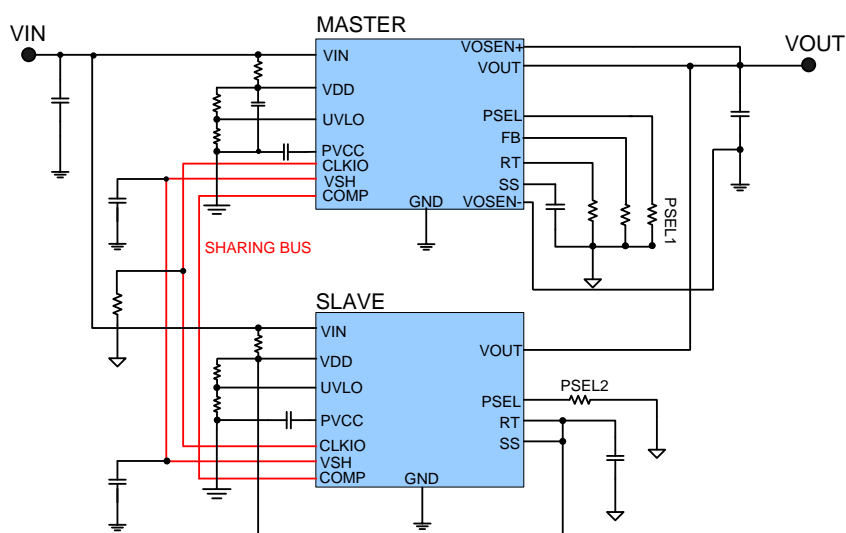


FIG.19 TYPICAL APPLICATION WITH 2-PHASES Parallel OPERATION

TABLE 2. PSEL PHASE PROGRAMMING

8-Phase Angle for Slave	PSEL1 (k Ω)	Phase Angle	Stand by	45°	90°	135°	180°	215°	270°	315°
	Open	PSEL 2 (k Ω)	Open	0	14.7	29.4	47	68	95.3	127
6-Phase Angle for Slave	PSEL1 (k Ω)	Phase Angle	Stand by	0°	60°	120°	180°	240°	300°	-
	29.4	PSEL 2 (k Ω)	Open	95.3	0	14.7	29.4	47	68	-

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APPLICATIONS INFORMATION: (Cont.)

The following waveforms and curves are shown the 2-phases interleaved operating performance. The switching node waveforms for master and slave module and sharing clock I/O pin are shown in Figure 20. In Figure 21, the output ripple can be reduced a lot compared individual operation. Regarding the efficiency performance, Figure 22 shows the comparison of individual and 2-phases interleaved operation. If the loading current increases around 40A, the current sharing performance is shown in Figure 23.

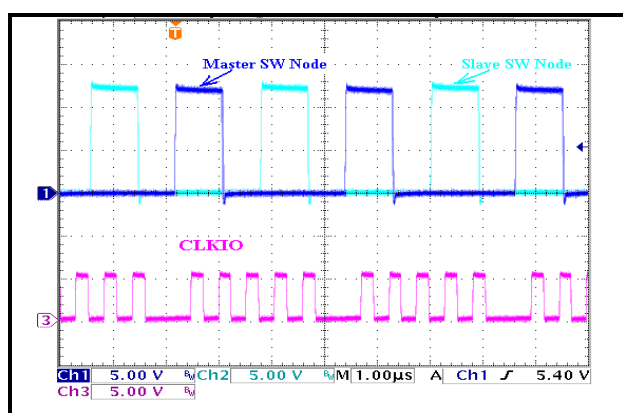


FIG.20 SW NODE of MASTER/SLAVE AND CLKIO

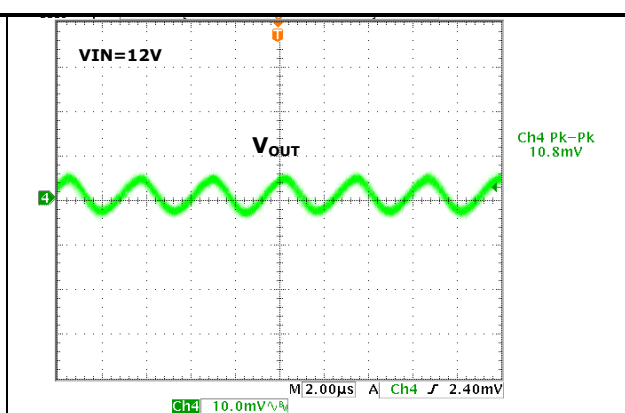


FIG.21 3.3 VOUT OUTPUT RIPPLE, at 10A LOAD CURRENT

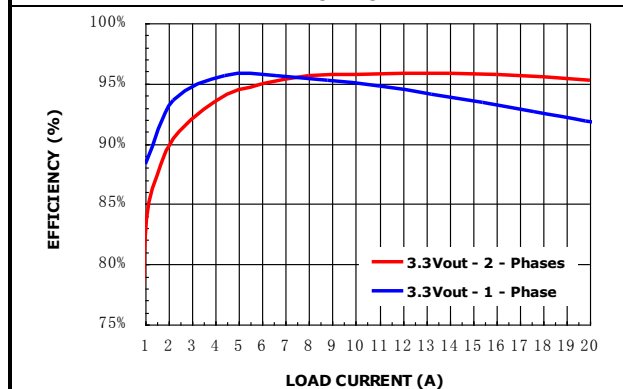


FIG.22 EFFICIENCY V.S. LOAD CURRENT (12VIN, 3.3VOUT, 1-PHASE and 2-PHASES)

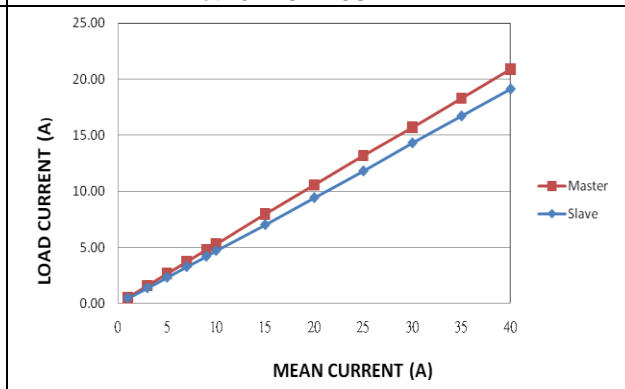


FIG.23 CURRENT SHARE V.S. LOAD CURRENT (12VIN, 3.3VOUT, 2-PHASES)

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APPLICATIONS INFORMATION: (Cont.)

Dual Outputs with Clock Synchronous

A connection diagram for two controllers sharing phase information and synchronized to each other but having different output voltages is shown in Figure 24. The controllers are all control loop masters (SS not pulled to VDD) and control their own output voltages independently. One device is configured as a CLK master (RT not tied to VDD) and is the clock generator for the CLK slaves. Picking the PSEL resistors is the same as before in TABLE 2. If one of the CLK slaves experiences a fault, that converter only shuts down, and enters the hiccup restart mode. If the CLK master controller senses an over current, it stops sending CLKIO pulses to the slaves, causing them to stop. The master then enters a hiccup recovery mode. In any system configured to have a CLK master and CLK slaves, a 10-k Ω resistor connected from CLKIO to GND is required.

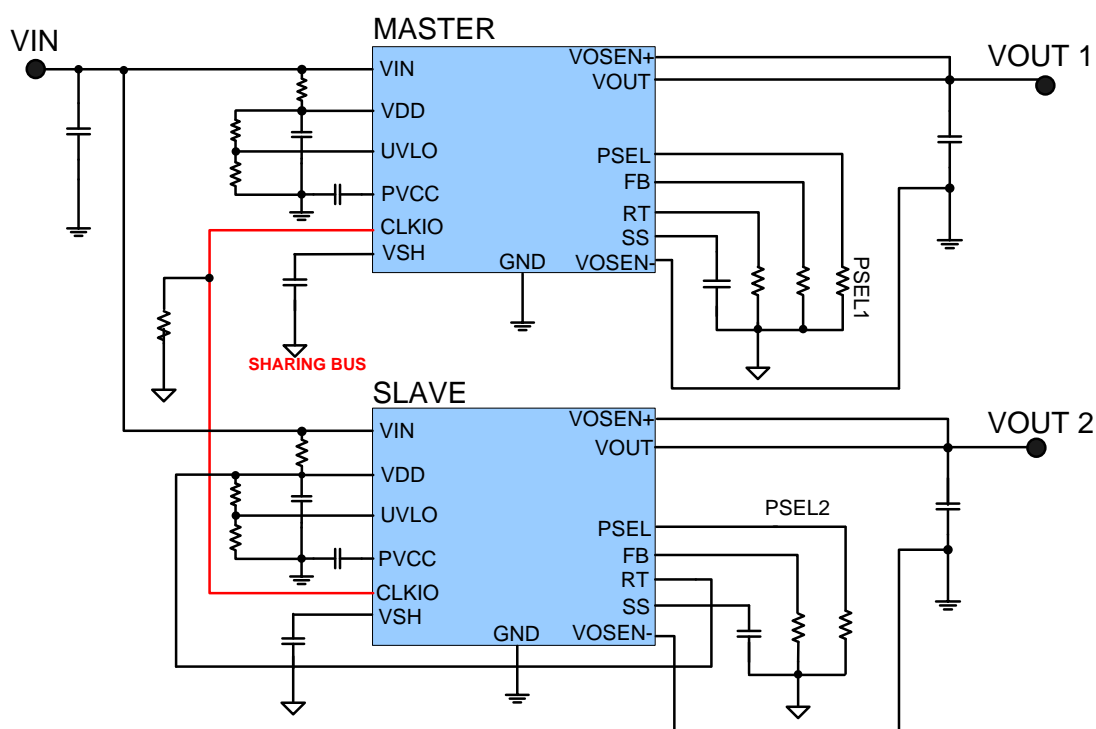


FIG.24 TYPICAL APPLICATION FOR DUAL OUTPUTS OPERATION

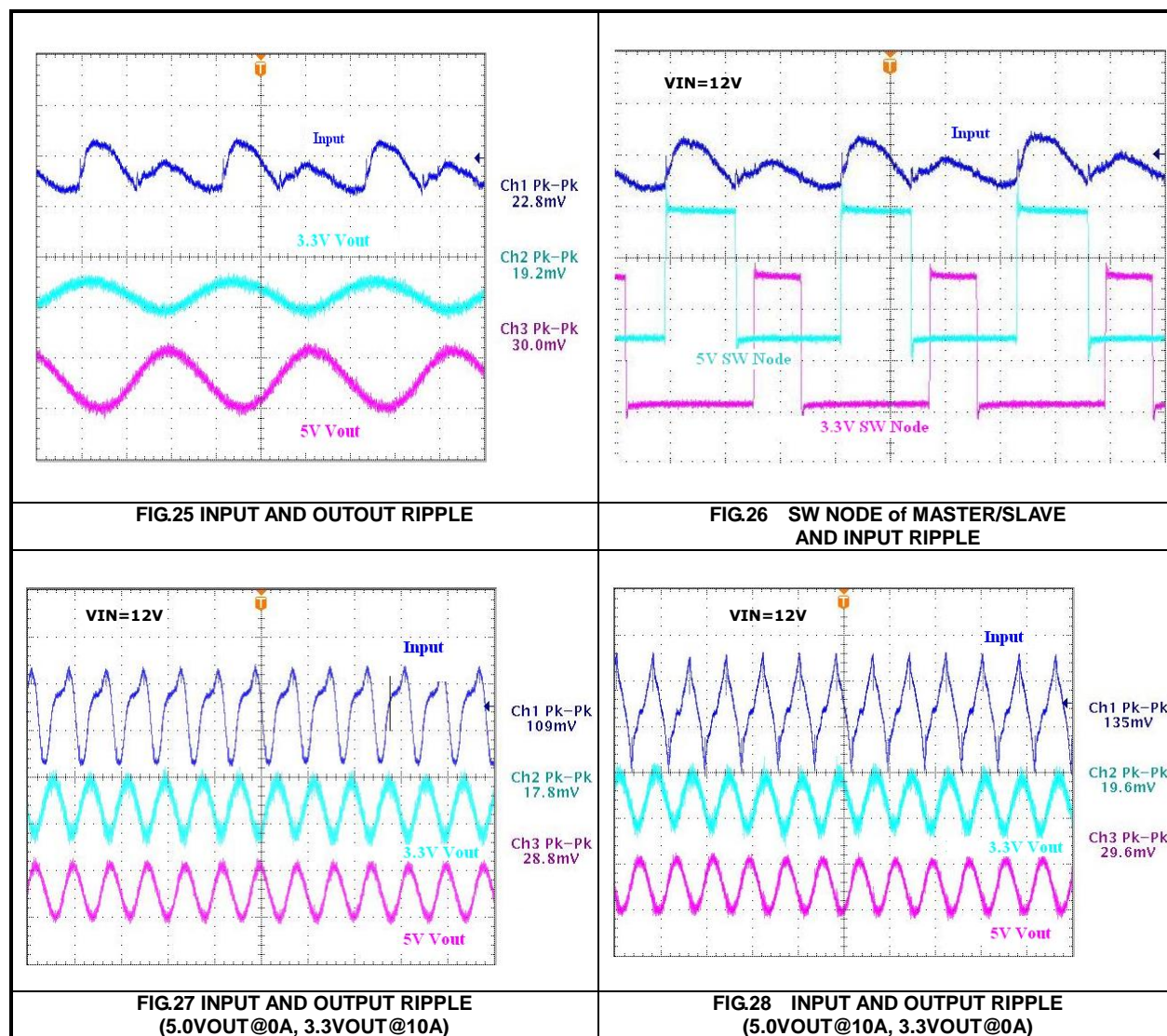
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APPLICATIONS INFORMATION: (Cont.)

The following waveforms and curves are shown the dual outputs with clock synchronous operating performance.

The input, each output ripple, and switching node waveforms are shown in Figure 25, 26, 27, and 28.



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APPLICATIONS INFORMATION: (Cont.)

PROGRAMMING OUTPUT VOLTAGE:

The HS2403 has an internal $0.7V \pm 1.0\%$ reference voltage. It only programs the dividing resistance R_{FB} which respects to FB pin and GND. The output voltage can be calculated as shown in Equation 1 and the resistance according to typical output voltage is shown in TABLE 1.

$$V_{OUT} = 0.7 \times \left(1 + \frac{10k}{R_{FB}} \right) \quad (EQ.1)$$

PROGRAMMING SWITCHING FREQUENCY:

Considering the efficiency and noise immunity, the HS2403 has setting the typical 300k Hz for initial operating frequency; its internal configuration resistor for operating frequency (R_{RT-IN}) is 91k ohms. If there is low output ripple noise or output capacitance limits application, the operating frequency can be increased by configuring an external resistor to RT pin in parallel. The calculation formula for operating frequency is shown as below.

$$R_{RT} = \left(\frac{3.675 \times 10^5}{F_{sw}^2} \right) + \left(\frac{2.824 \times 10^4}{F_{sw}} \right) - 5.355 \quad (EQ.2)$$

Where:

F_{sw} is the desired switching frequency in kHz.

R_{RT} is equivalent resistance for switching frequency setting in kohms and is calculated between RT and GND pins.

The HS2403 has integrated 91k Ω resistance (R_{RT-IN}). Therefore, the equivalent resistance of R_{RT} can be expressed in Equation 3.

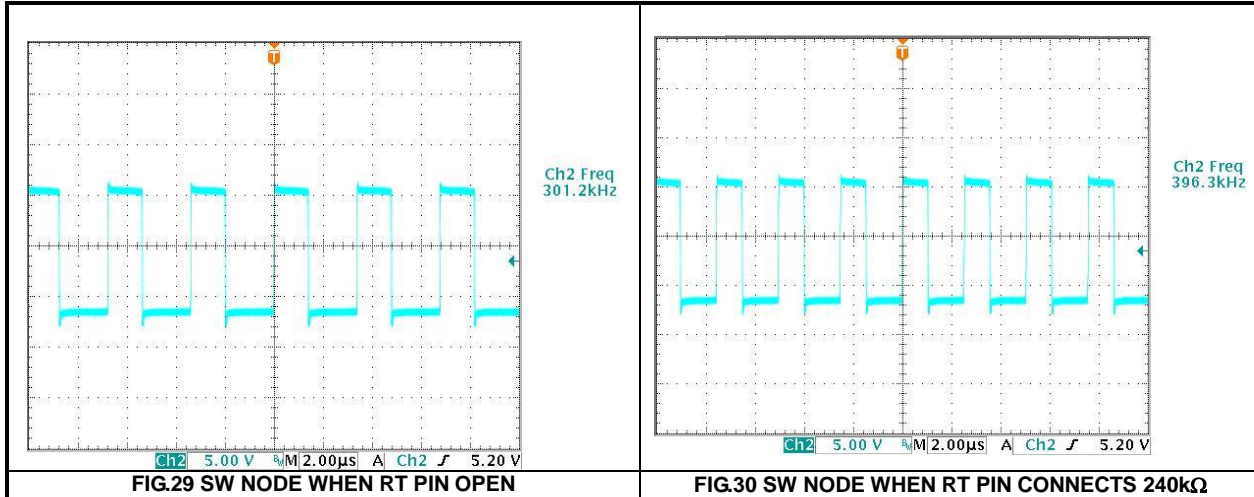
$$R_{RT} = \frac{R_{RT-EX} \times R_{RT-IN}}{R_{RT-EX} + R_{RT-IN}} \quad (EQ.3)$$

The following waveforms show the 300k Hz typical switching frequency (Let RT pin open) and 400k Hz which RT pin connects a 240k Ω resistor to GND.

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20A, High Efficiency Power Module

APPLICATIONS INFORMATION: (Cont.)



PROGRAMMING SOFT-START WITH OUTPUT PRE-BIAS:

The soft-start time of HS2403 can be programmable by connecting a capacitor from SS pin to GND pin. An internal current source charges this capacitor providing a linear ramp voltage. This ramp voltage is the effective reference to the error amplifier while it is less than the 0.7V internal reference. The time required for the SS pin to ramp from GND to 0.7V is soft-start time. For output that is not pre-biased, that time is given in Equation 4.

$$T_{SS} = \frac{V_{REF} \times (0.022 \mu + C_{SS})}{I_{SS}} \quad (EQ.4)$$

Where:

T_{SS} is the soft-start time in seconds.

V_{REF} is internal reference voltage, 0.7V typical value.

C_{SS} is the capacitor from SS to GND in μF .

I_{SS} is internal soft-start current source, 15 μA typical value.

The following waveforms show the output start-up and soft start when SS open and SS pin connects an external capacitor.

HS2403

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APPLICATIONS INFORMATION: (Cont.)

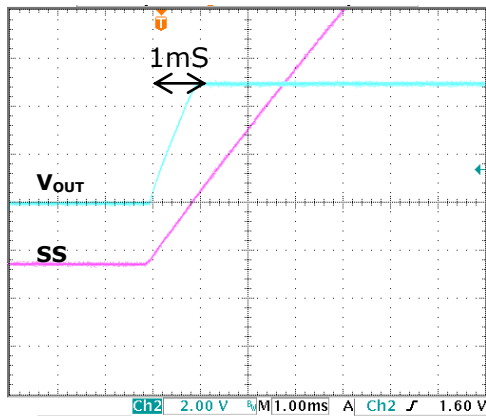


FIG.31 OUTPUT AND SS WHEN SS PIN OPEN

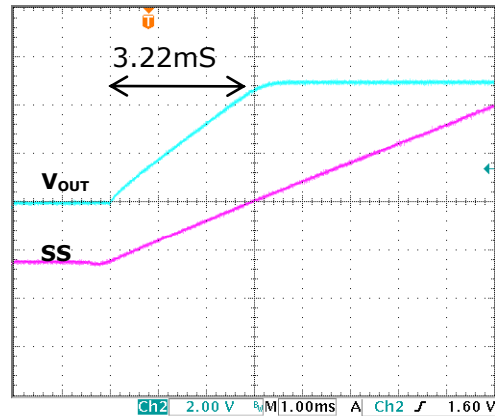


FIG.32 OUTPUT AND SS WHEN SS PIN CONNECT 47nF

Considering the output of HS2403 has a pre-existing voltage, the internal soft-start current source is held to a lower value than normal until the PWM signal becomes active. This occurs as the SS pin voltage exceeds the FB pin voltage and the COMP pin moves up into the ramp range, causing the first pulse. At that point, the internal soft-start current is shifted to 15uA nominal. The Figure 33 and Figure 34 illustrate this operation.

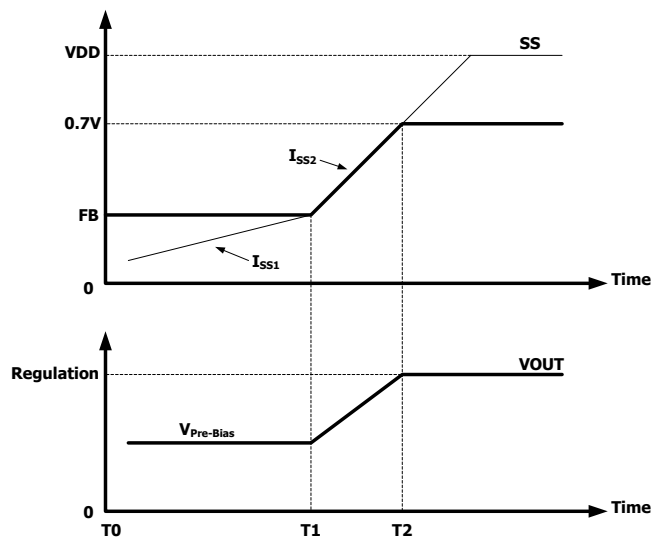


FIG.33 SOFT-SATRT WAVEFORM WITH PRE-BIASED OUTPUT

HS2403

20A, High Efficiency Power Module

APPLICATIONS INFORMATION: (Cont.)

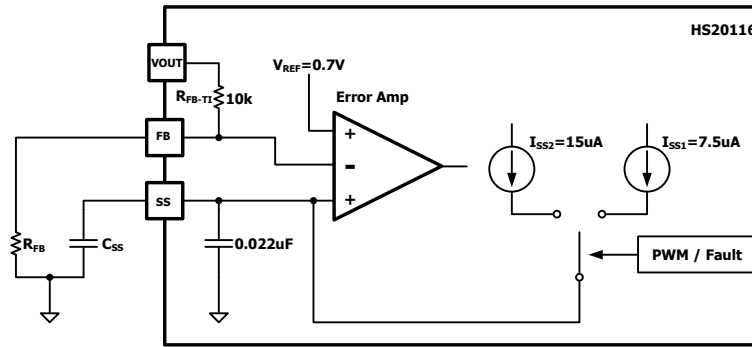


FIG.34 SOFT-SATRT IMPLEMENTATION

Based on Figure 34, the soft-start time with output pre-existing voltage can be calculated as below.

$$T_1 = \left(\frac{0.022\mu + C_{SS}}{I_{SS1}} \right) \times \left(\frac{V_{Pre-Bias} \times R_{FB}}{R_{FB-TI} + R_{FB}} \right) \quad (EQ.5)$$

$$T_2 = \left(\frac{0.022\mu + C_{SS}}{I_{SS2}} \right) \times \left(V_{REF} - \frac{V_{Pre-Bias} \times R_{FB}}{R_{FB-TI} + R_{FB}} \right) \quad (EQ.6)$$

$$T_{SS} = T_1 + T_2 \quad (EQ.7)$$

Where:

T1 is the time to the first PWM pulse in seconds.

T2 is the time from the first PWM pulse until regulation in seconds.

TSS is the total soft-start time.

CSS is the capacitor from SS to GND in uF.

ISS1 is internal soft-start current source, 7.5uA typical value.

ISS2 is internal soft-start current source, 15uA typical value.

VREF is internal reference voltage, 0.7V typical value.

RFB-TI is internal voltage dividing resistor, 10k ohms typical value.

RFB is external voltage dividing resistor.

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APPLICATIONS INFORMATION: (Cont.)

ON/OFF CONTROL AND PGOOD INDICATION:

Figure 35 shows a remote ON/OFF control of HS2403 by using UVLO pin. Pulling UVLO low than threshold voltage (0.9V typ.) will be disabled the HS2403. The external pull-down device can use open drain or open collector devices. The turn-on/turn-off waveforms with PGOOD are shown in Figure 36 and 37.

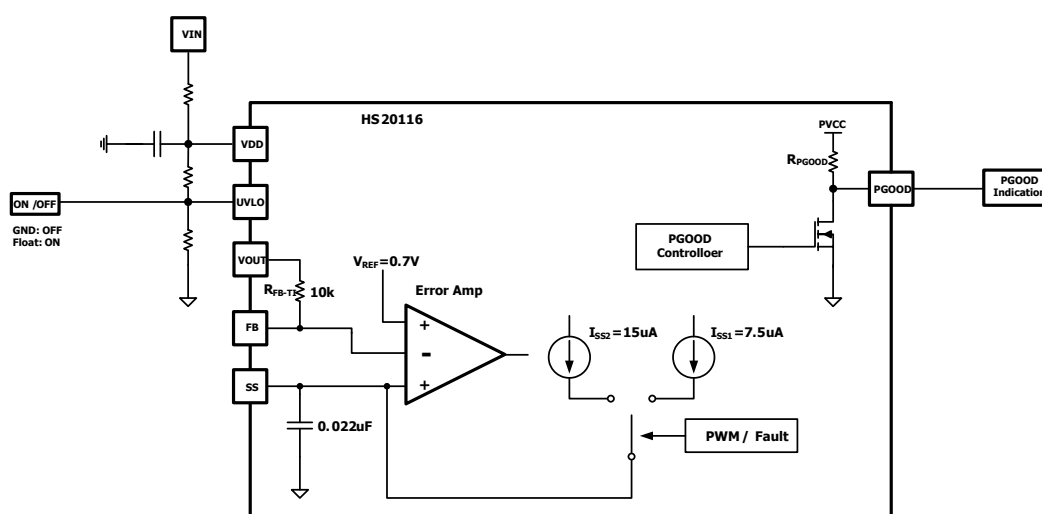
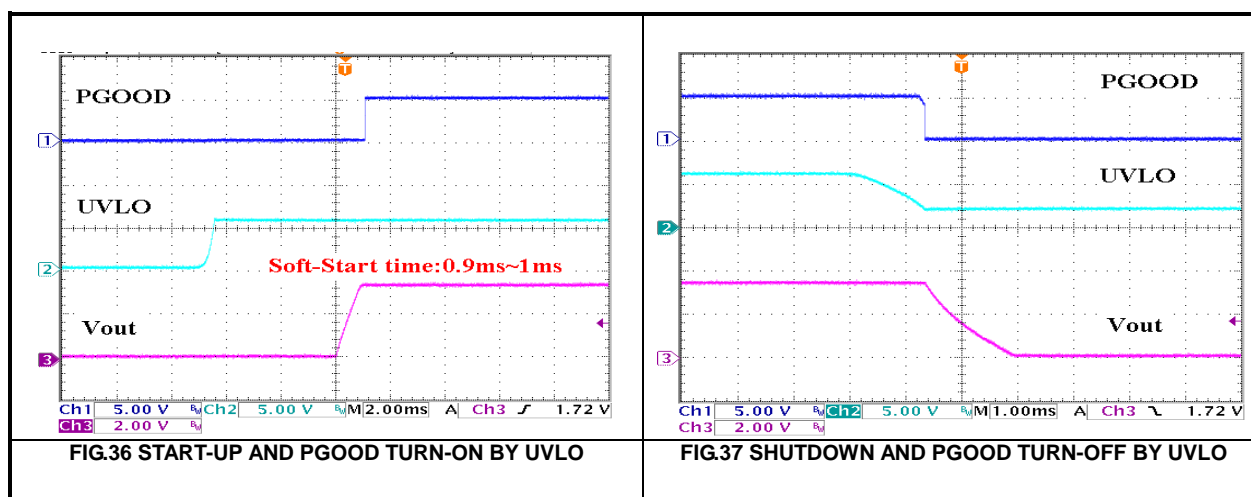


FIG.35 ON/OFF CONTROL AND PGOOD IMPLEMENTATION



HS2403

20A, High Efficiency Power Module

APPLICATIONS INFORMATION: (Cont.)

OVER CURRENT PROTECTION:

The over-current function protects the converter from a shorted output by using the equivalent series resistor of inductor, DCR, to monitor the current. A resistor networking of ILIM and VSH pins (R_{ILIM} and R_{VSH}) programs the over-current trip level. If over-current is detected, the output immediately shuts off, it cycles the soft-start function in a hiccup mode (7 dummy soft-start time-outs, then up to one real one) to provide fault protection. If the shorted condition is not removed, this cycle will continue indefinitely. The over-current function will trip at a peak inductor current (I_{PEAK}) determined by Equation 8.

$$I_{PEAK} = \frac{I_{ILIM} \times (R_{ILIM} // R_{VSH}) - \left(\frac{V_{RMP}}{VIN} \right) \times V_{VSH} - \Delta V_{PHASE}}{G_{CS} \times DCR} - \frac{(VIN - VOUT)}{2 \times Fs \times L} \times \frac{VOUT}{VIN} \quad (EQ.8)$$

Where:

Symbol	Parameter	Conditions	Min.	Typ.	Max.	Unit
I_{ILIM}	ILIM current source	Note 3	21.5	23.5	25.5	uA
V_{RMP}	Ramp voltage	Note 3	420	500	525	mV
V_{VSH}	Sharing Reference	Note 3	1.7	1.8	1.9	V
ΔV_{PHASE}	8 Phase Reference	Note 3	-	31	-	mV
	6 Phase Reference	Note 3	-	42	-	mV
G_{CS}	Current Sensing Gain	Note 3	11.25	12.5	13.75	V/V
DCR	equivalent series resistor of inductor	$T_c=25^{\circ}C$	-	3.0	3.6	m Ω
L	L0 Inductance	Current =0A, $T_c=25^{\circ}C$	1.44	1.8	2.16	uH
	Lsat Inductance	Current =38A, $T_c=25^{\circ}C$, Refer to L0 (typ)	-	1.26	-	uH
$R_{ILIM-IN}$	Internal resistor between ILIM and VOUT pins		83.6	84.5	85.4	k Ω
R_{VSH-IN}	Internal resistor between VSH and ILIM pins		1.98	2	2.02	Meg Ω

And also,

$$R_{ILIM} = R_{ILIM-IN} // R_{ILIM-EX} \quad \text{and} \quad R_{VSH} = R_{VSH-IN} // R_{VSH-EX} \quad (EQ.9)$$

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20A, High Efficiency Power Module

APPLICATIONS INFORMATION: (Cont.)

INPUT AND OUTPUT CAPACITORS:

Place the decoupled ceramic capacitors to control the high frequency voltage overshoot and bulk capacitor to supply the current needed each time module turns-on. The important parameters for bulk capacitor are voltage rating and the RMS current rating. For reliable operation, the bulk capacitor selects the voltage and current rating above maximum input voltage and highest RMS current required.

The bulk output capacitors C_{OUT} is chosen with low enough effective series resistance (ESR) to meet the output voltage ripple and transient requirements. C_{OUT} can be low ESR tantalum capacitor, low ESR polymer capacitor or ceramic capacitor. The typical capacitance is 600 μ F and decoupled ceramic output capacitors are used. Additional output filtering may be required by the system designer, if further reduction of output ripple or dynamic transient spike is required.

RECOMMENDATION LAYOUT GUIDE:

In order to achieve stable, low losses, less noise or spike, and good thermal performance some layout considerations are necessary. The recommendation layout is shown as Figure 38.

1. A synchronous BUCK converter has two primary current loops. One is the input current loop which carries high AC discontinuous current and the other is the output current loop carrying a high DC continuous current. The input current loop includes the input capacitors, the main switching MOSFET, the inductor, the output capacitors and the ground path back to input capacitors. To keep this loop as small as possible, it is generally good practice to place some ceramic capacitance directly between the drain of the high-side MOSFET(VIN) and the source of the low-side MOSFET(PGND).
2. The SW node area should be as small as possible to reduce the parasitic capacitance and minimize the radiated emissions.
3. It is required to separate properly the circuit grounds. The return path for the pins associated with the power stage should be through PGND. The other pins especially for those sensitive pins such as FR, RT and ILIM should be through the low noise GND. The GND and PGND plane are suggested to be connected at output capacitor with single trace.
4. A minimum 2.2 μ F ceramic capacitor must be placed as close to the VDD pin and connect to PGND directly through the via.
5. A minimum 0.1 μ F ceramic capacitor must be placed as close to the PVCC pin and connect to PGND directly through the via.

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APPLICATIONS INFORMATION: (Cont.)

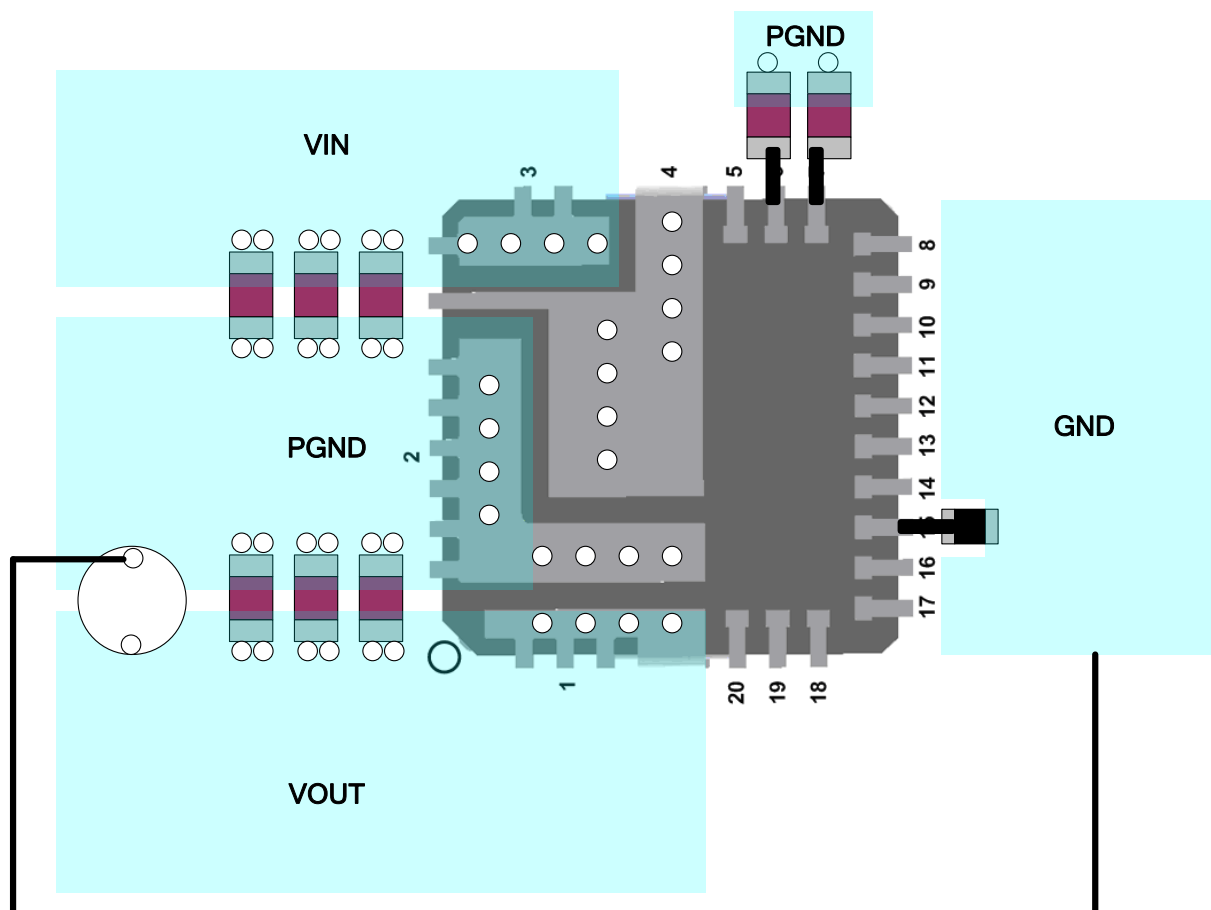


FIG.38 RECOMMENDATION LAYOUT (Top)

NOTES:

1. The trip values are tested at $T_A = 25\text{ }^{\circ}\text{C}$, $C_{in}=22\mu\text{F/Ceramic}\times 5$, $C_{out}=100\mu\text{F/Ceramic}\times 6$.
Test Board Information: 60mmx60mmx1.6mm, 4 layers, 2oz.

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APPLICATIONS INFORMATION: (Cont.)

THERMAL CONSIDERATIONS:

All of thermal testing condition is complied with JEDEC EIJ/JESD 51 Standards. Therefore, the test board size is 80mm×80mm×1.6mm with 4 layers, 2oz. The case temperature of module sensing point is shown as Figure 39. Then $R_{th(j-a)}$ is measured with the component mounted on an effective thermal conductivity test board on 0 LFM condition. The HS2403 module is designed for using when the case temperature is below 110°C regardless the change of output current, input/output voltage or ambient temperature. The de-rating load current in different output voltage are shown in Figure 40, 41, 42, and 43. It would be convenient for user to confirm and estimate module's approximate performance according to actual operating conditions in beginning of design.

Sensing Point (Defined case temperature)

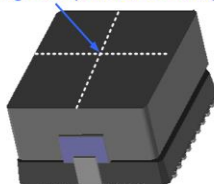
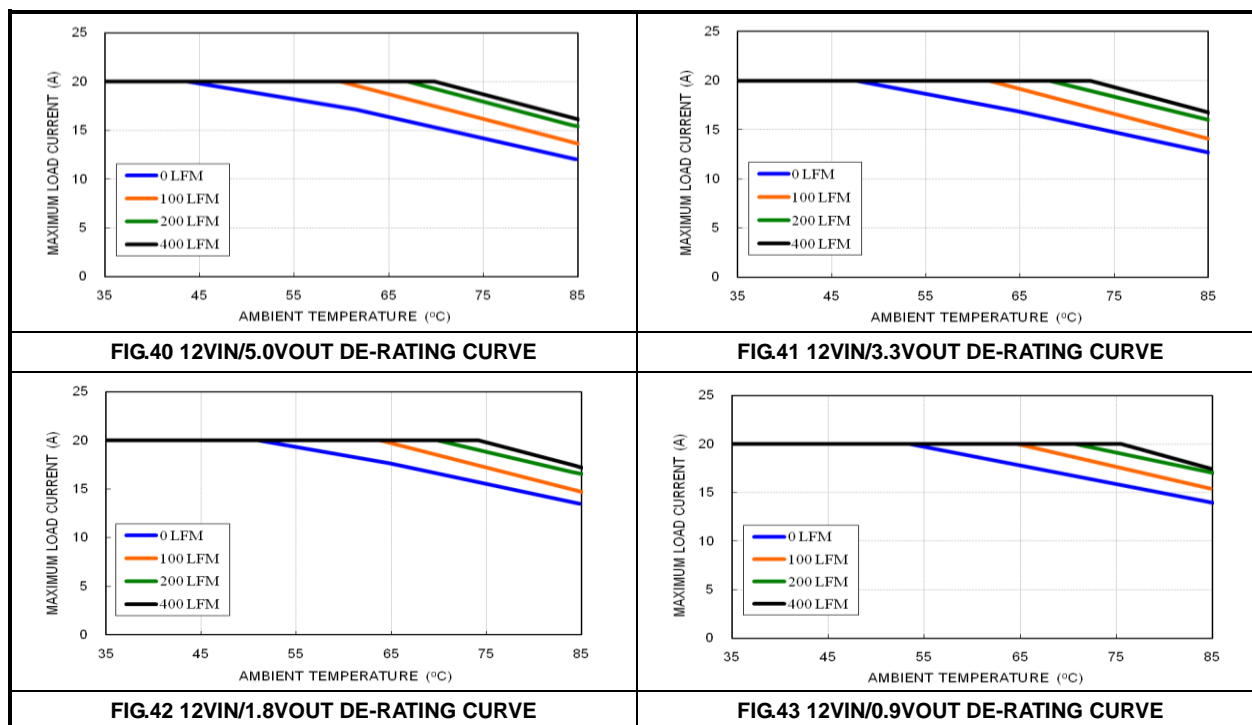


FIG.39 CASE TEMPERATURE SENSING POINT



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THERMAL PERFORMANCE (Cont.):

Force Air Flow Thermal Management for 22A Applications:

Some of applications will over 20A under forced air flow. Here is an example for 22A output current application when the system has forced air flow to do the heat transferring. The thermal evaluation set-up by using wind tunnel is shown as below.

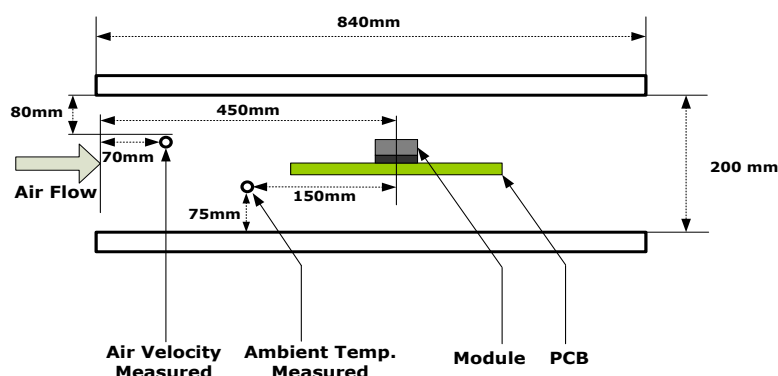


Figure. 44 Thermal Measurement Set-up

There are two cases for thermal management reference according to difference PCB size and output voltage. The measurement result is shown as below table.

TABLE 3 THERMAL MAGETMENT REFERENCE FOR 22A APPLICATION

Vin=12V / Vout=5 / PVCC=8V / Iout=22A When Case Temperature of module (Tc)=110°C				
PCB Size (mm)	Layer	Copper Thickness (Oz)	Ambient Temp. (°C)	Air Velocity (LFM)
80 x 80 x 1.6	4	2	25	25
Vin=12V / Vout=5 / PVCC=8V / Iout=22A When Case Temperature of module (Tc)=85°C				
35 x 20 x 1.2	4	2	25	585
Vin=12V / Vout=3.3 / PVCC=8V / Iout=22A When Case Temperature of module (Tc)=110°C				
80 x 80 x 1.6	4	2	25	0
Vin=12V / Vout=3.3 / PVCC=8V / Iout=22A When Case Temperature of module (Tc)=85°C				
35 x 20 x 1.2	4	2	25	535

NOTES:

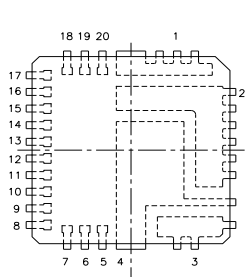
- The measurement result shown on table 3 is only for reference based on specific condition as Fig-44, not applied to the overall applications. It may affect device reliability or cause permanent damage when the operation is beyond this recommendation. Needs to confirm with manufactory if condition will be changed.

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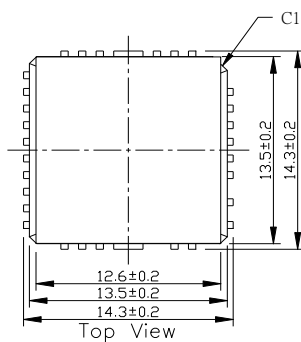
20A, High Efficiency Power Module

PACKAGE OUTLINE DRAWING:

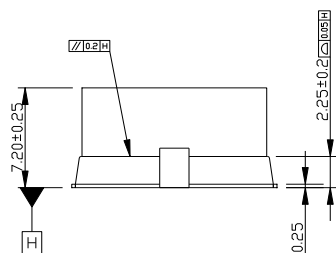
Unit: mm



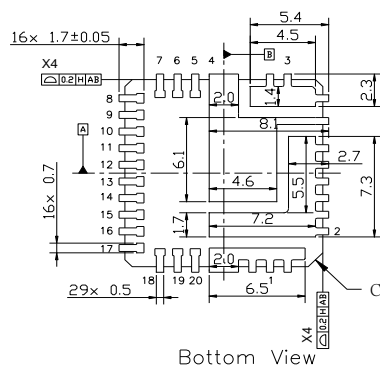
Top View



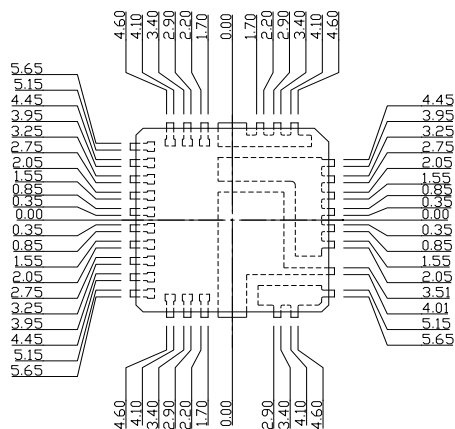
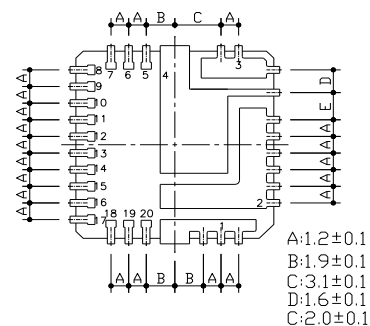
Top View



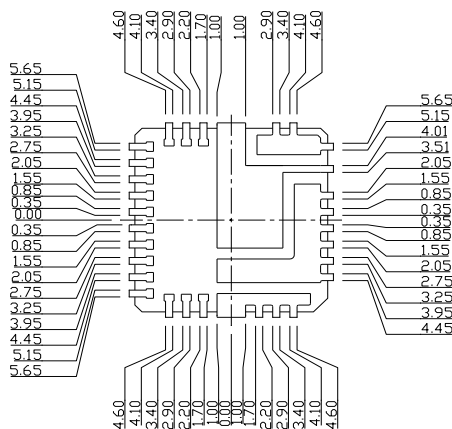
Side View



Bottom View



Top View



Bottom View

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REFLOW PARAMETERS:

Lead-free soldering process is a standard of making electronic products. Many solder alloys like Sn/Ag, Sn/Ag/Cu, Sn/Ag/Bi and so on are used extensively to replace traditional Sn/Pb alloy. Here the Sn/Ag/Cu alloy (SAC) are recommended for process. In the SAC alloy series, SAC305 is a very popular solder alloy which contains 3% Ag and 0.5% Cu. It is easy to get it. Figure 45 shows an example of reflow profile diagram. Typically, the profile has three stages. During the initial stage from 70°C to 90°C, the ramp rate of temperature should be not more than 1.5°C/sec. The soak zone then occurs from 100°C to 180°C and should last for 90 to 120 seconds. Finally the temperature rises to 230°C to 245°C and cover 220°C in 30 seconds to melt the solder. It is noted that the time of peak temperature should depend on the mass of the PCB board. The reflow profile is usually supported by the solder vendor and user could switch to optimize the profile according to various solder type and various manufactures' formula.

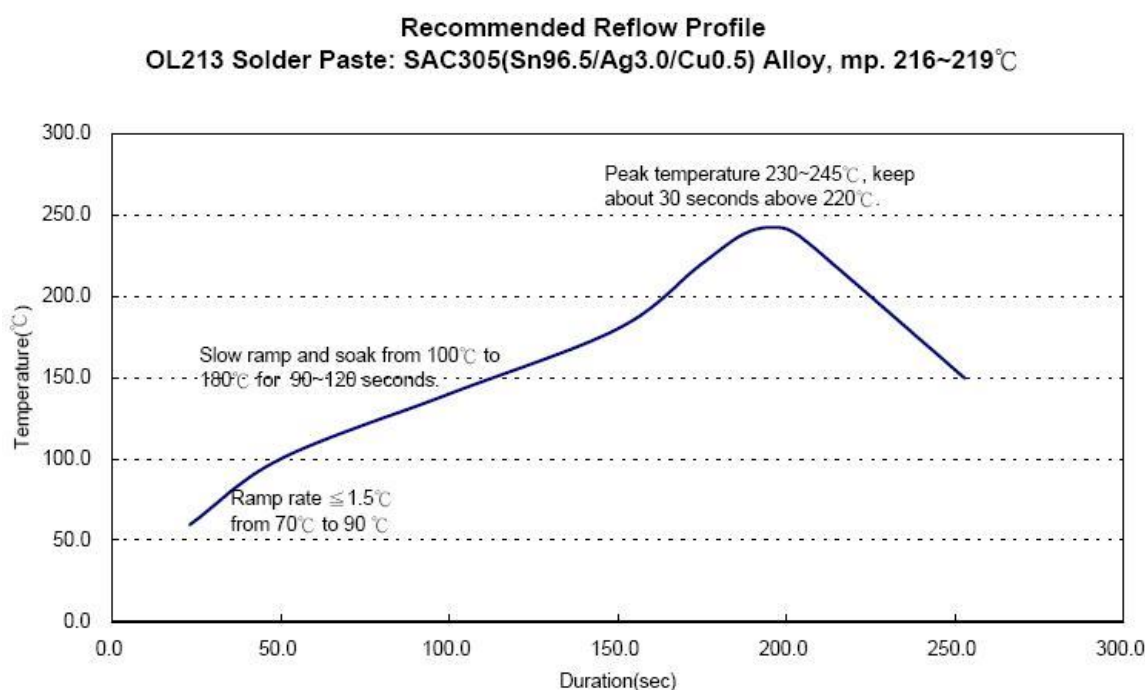


FIG.45 RECOMMENDATION REFLOW PROFILE

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STORAGE AND HANDLING:

MOISTURE BARRIER BAG:

Although POL module is a kind of package devices and its inner components are all protected by the package compounds, it is still probably damaged during soldering process if moisture is absorbed into package. The modules firstly are packed in a reel, and then an aluminum moisture barrier bag is used to pack the reel in order to prevent moisture absorption. Silica gel is put into the aluminum moisture barrier bag as absorbent material.

STORAGE:

The POL module pack storage follows the JEDEC J-STD-033B01 and J-STD-020C standards. Table 4 is the floor life and moisture sensitive level defined by JEDEC. POL module is classified into level 3. The floor life starts to estimate while the aluminum moisture barrier bag is opened. Under the storage situation of 30°C/60% RH, the device can keep 168 hours floor life after the pack opened. If there are unused POL modules remained, they should be resealed in original moisture barrier bag as soon as possible. However, in case of the modules' floor life exceeding the defined time period, baking process will be necessary to dehumidify. The method is to bake the module in an oven at 125°C/1% RH (e.g. hot nitrogen gas atmosphere) for 48 hours.

HANDLING AND OTHERS:

To protect the POL module and to make sure its normal use, something should be noticed as below.

1. Please handle the POL module carefully to avoid unnecessary mechanism stress on it. Improperly external stress may cause unexpected damage.
2. The ESD wrist strap, ESD shoe strap or anti-electrostatic gloves are recommended to be used whenever handling POL module.
3. If cleaning the module is necessary, please use alcohol or IPA solution to clean it under normal room temperature. Avoid the use of unspecified solvent.

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STORAGE AND HANDLING: (Cont.)

TABLE 4 MOISTURE CLASSIFICATION LEVEL AND FLOOR LIFE

Level	Floor Life (out of bag) at factory ambient $\leq 30^{\circ}\text{C}/60\% \text{ RH}$ or as stated
1	Unlimited at $\leq 30^{\circ}\text{C}/85\% \text{ RH}$
2	1 year
2a	4 weeks
3	168 hours
4	72 hours
5	48 hours
5a	24 hours
6	Mandatory bake before use. After bake, must be reflowed within the time limit specified on the label.

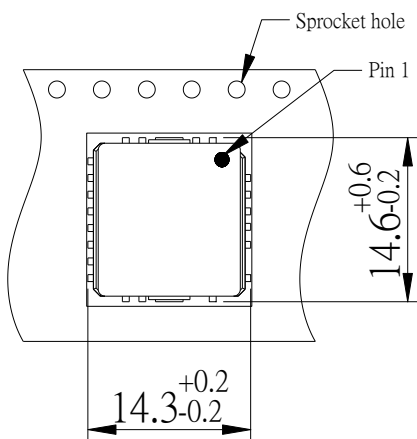
HS2403

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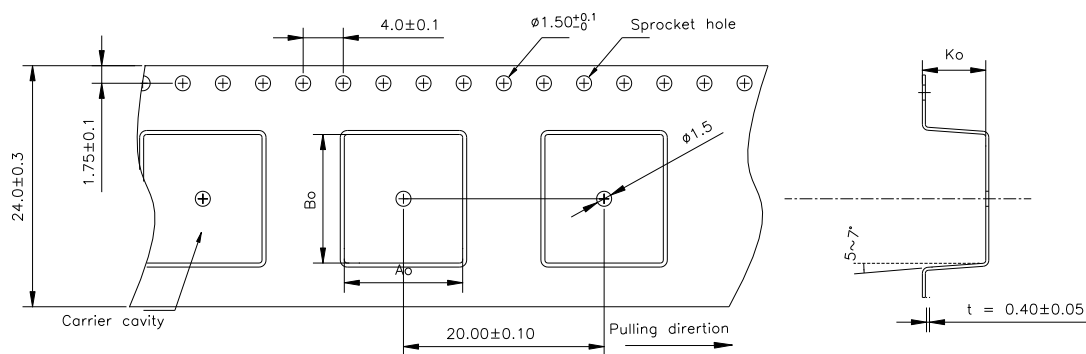
PACKING INFORMATION:

Unit: mm

Tape and Reel Packing



PACKAGE IN TAPE LOADING ORIENTATION



TAPE DIMENSION

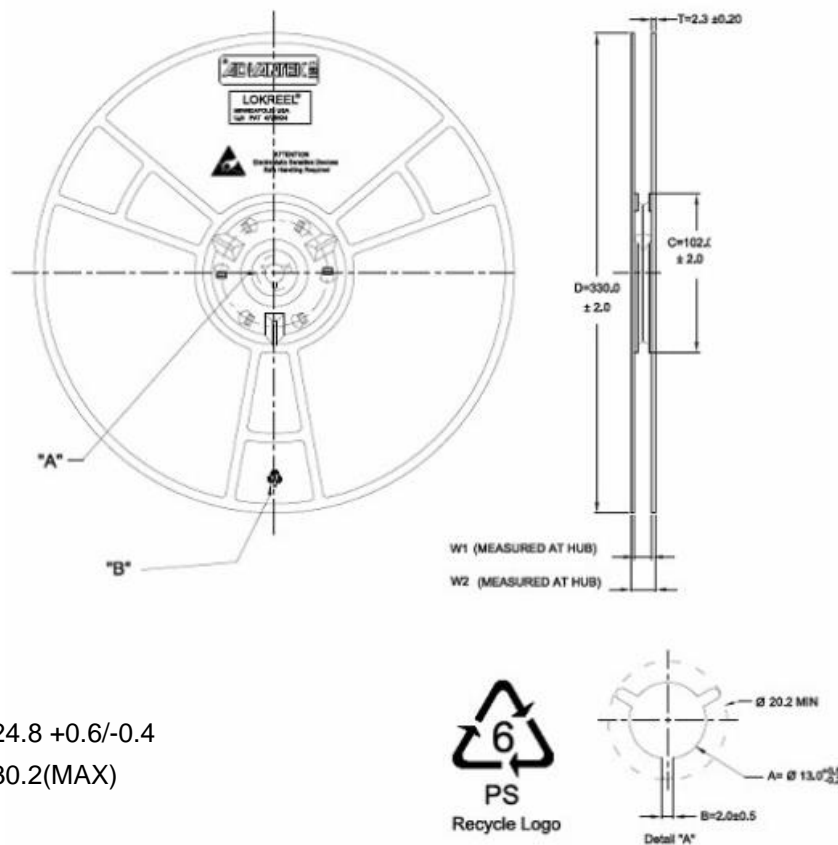
A0	14.70 ± 0.10
B0	15.30 ± 0.10
K0	7.6 ± 0.10

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PACKING INFORMATION: (Cont.)

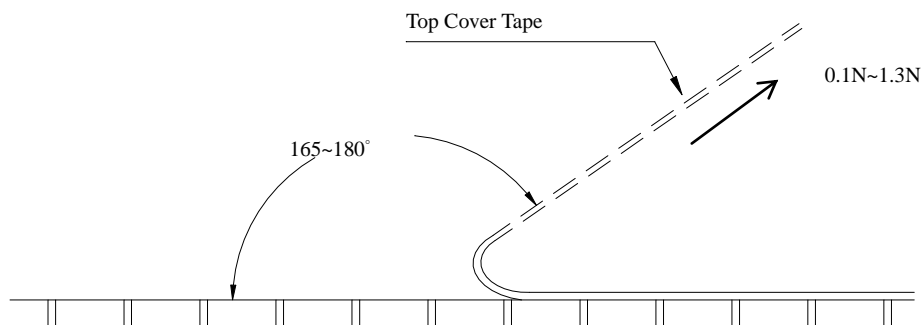
Unit: mm



Peel Strength of Top Cover Tape

The peel speed shall be about 300mm/min.

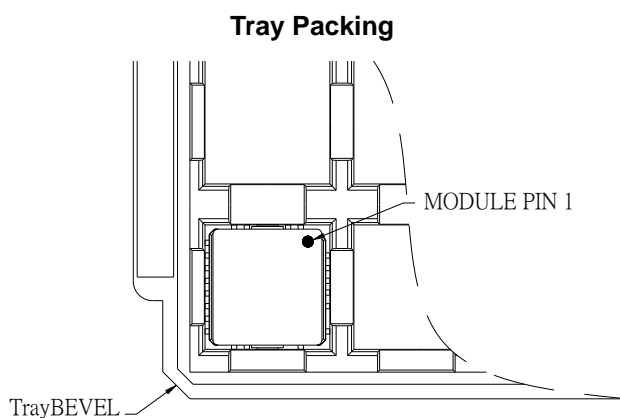
The peel force of top cover tape shall between 0.1N to 1.3 N



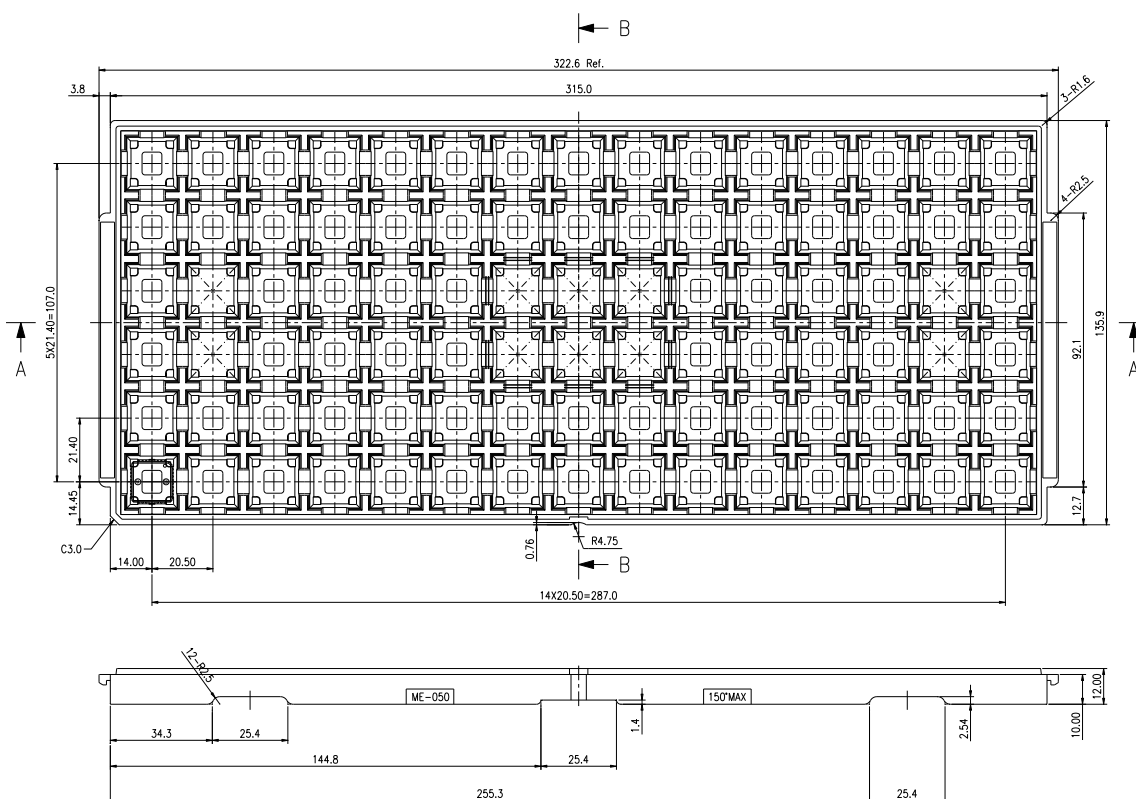
20A, High Efficiency Power Module

PACKING INFORMATION: (Cont.)

Unit: mm



PACKAGE IN TRAY LOADING ORIENTATION



TRAY DIMENSION